

# 6MBI100VW-060-50

**IGBT Modules** 

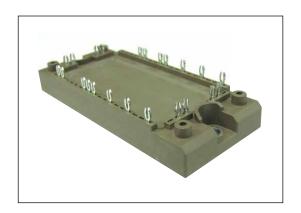
# IGBT MODULE (V series) 600V / 100A / 6 in one package

# ■ Features

Compact Package P.C.Board Mount Low Vce (sat)

# ■ Applications

Inverter for Motor Drive
AC and DC Servo Drive Amplifier
Uninterruptible Power Supply
Industrial machines, such as welding machines



# ■ Maximum Ratings and Characteristics

# ● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Er	Collector-Emitter voltage				600	V	
Gate-Emitte	Gate-Emitter voltage				±20	V	
rter	Collector current		Continuous	Tc=80°C	100		
Collector			1ms	Tc=80°C	200	^	
Collector cu					100	А	
			1ms		200		
Collector po	Collector power dissipation		1 device		335	W	
Junction temperature		Tj			175	°C	
Operating junciton temperature (under switching conditions)		Tjop			150		
Case temperature		Tc			125		
Storage temperature		Tstg			-40 to +125		
Isolation voltaç	between terminal and copper base (*1) between thermistor and others (*2)	Viso	AC : 1min.		2500	VAC	
Screw torque	Mounting (*3)	-	M5		3.5	N m	

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note \*3: Recommendable value: 2.5-3.5 Nm (M5)

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# ● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items		Symbolo	Conditions		Characteristics			Units
		Symbols			min.	typ.	max.	Units
	Zero gate voltage collector current	Ices	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 600V		-	-	1.0	mA
	Gate-Emitter leakage current	e current $I_{GES}$ $V_{GE} = 0V, V_{GE} = \pm 20V$			-	-	200	nA
	Gate-Emitter threshold voltage	V <sub>GE (th)</sub>	V <sub>CE</sub> = 20V, I <sub>C</sub> = 100mA		6.2	6.7	7.2	V
	Collector-Emitter saturation voltage	V <sub>CE (sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>C</sub> = 100A	Tj=25°C	-	2.05	2.50	V
				Tj=125°C	-	2.35	-	
				Tj=150°C	-	2.55	-	
		V <sub>CE (sat)</sub> (chip)	V <sub>GE</sub> = 15V I <sub>C</sub> = 100A	Tj=25°C	-	1.60	2.05	
				Tj=125°C	-	1.90	-	
				Tj=150°C	-	2.10	-	
	Internal gate resistance	Rg(int)	-		-	9	-	Ω
	Input capacitance	Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz		-	6.4	-	nF
Inverter		ton		-	0.36	1.20	μs	
	Turn-on time	tr	Vcc = 300V	-	0.25	0.60		
		tr (i)	Ic = 100A -V <sub>GE</sub> = +15 / -15V	-	0.07	-		
		toff	$R_G = 13\Omega$	-	0.52	1.20		
	Turn-off time	tf			-	0.03		0.45
	Forward on voltage	V <sub>F</sub> (terminal)	I <sub>F</sub> = 100A	Tj=25°C	-	2.05	2.50	V
				Tj=125°C	-	1.95	-	
				Tj=150°C	-	1.90	-	
		V <sub>F</sub> (chip)	I <sub>F</sub> = 100A	Tj=25°C	-	1.60	2.05	
				Tj=125°C	-	1.50	-	
				Tj=150°C	-	1.45	-	
	Reverse recovery time	trr	I <sub>F</sub> = 100A		-	-	0.35	μs
호	Danistana a	R	T = 25°C		-	5000	-	Ω
Thermistor	Resistance		T = 100°C		465	495	520	
Ţ	B value	В	T = 25 / 50°C		3305	3375	3450	K

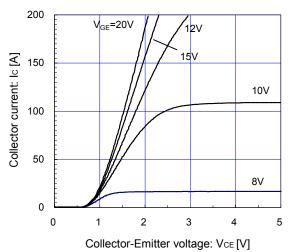
### ● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items		Conditions	min.	typ.	max.	Units
Thormal registance (Adayies)	Rth(j-c)	Inverter IGBT	-	-	0.45	°C/W
Thermal resistance (1device)		Inverter FWD	-	-	0.80	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-	

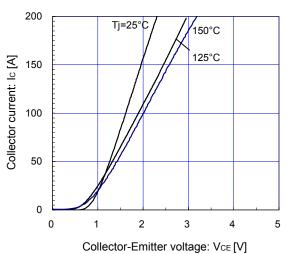
Note  $^{\star}4$ : This is the value which is defined mounting on the additional cooling fin with thermal compound.

# **■** Characteristics (Representative)

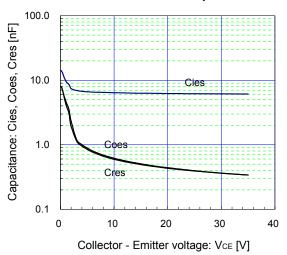
 $\label{eq:continuous} \begin{tabular}{ll} \end{tabular} \begin{tabular}{ll} \end{tabular} Inverter \end{tabular} ] $$ Collector current vs. Collector-Emitter voltage (typ.) $$ Tj= 25^{\circ}C / chip $$ $$ Tj= 25^{\circ}C$ 



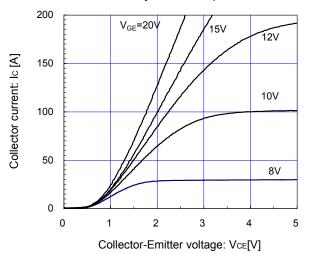
 $[Inverter] \\ Collector current vs. Collector-Emitter voltage (typ.) \\ V_{GE} = 15V / chip$ 



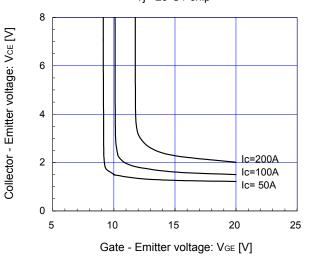
 $\label{eq:continuous} \begin{tabular}{ll} [Inverter] \\ Capacitance vs. Collector-Emitter voltage (typ.) \\ V_{GE}=0V, \ f= 1MHz, \ Tj= 25^{\circ}C \end{tabular}$ 



[ Inverter ] Collector current vs. Collector-Emitter voltage (typ.)  $Tj = 150^{\circ}C / chip$ 



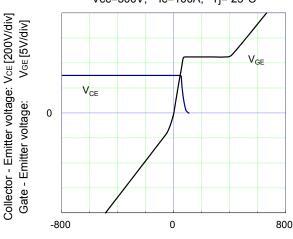
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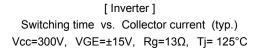


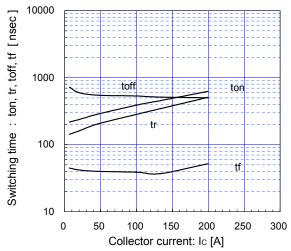
[ Inverter ]

Dynamic gate charge (typ.)

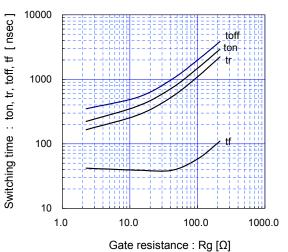
Vcc=300V, Ic=100A, Tj= 25°C



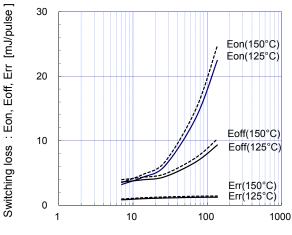




[Inverter]
Switching time vs. gate resistance (typ.)
Vcc=300V, Ic=100A, VGE=±15V, Tj= 125°C

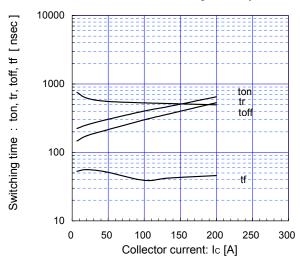


[ Inverter ]
Switching loss vs. gate resistance (typ.)
Vcc=300V, Ic=100A, VGE=±15V

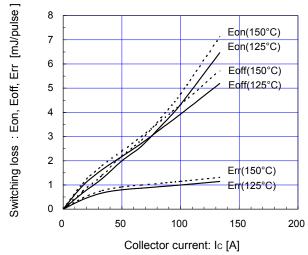


Gate resistance : Rg [Ω]

[ Inverter ] Switching time vs. Collector current (typ.) Vcc=300V, VGE= $\pm$ 15V, Rg=13 $\Omega$ , Tj= 150°C



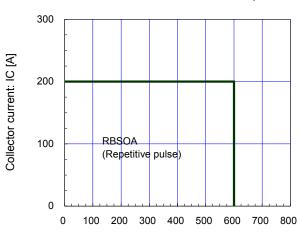
 $\label{eq:continuous} \begin{tabular}{ll} [Inverter] \\ Switching loss vs. Collector current (typ.) \\ Vcc=300V, VGE=\pm15V, Rg=13\Omega \\ \end{tabular}$ 



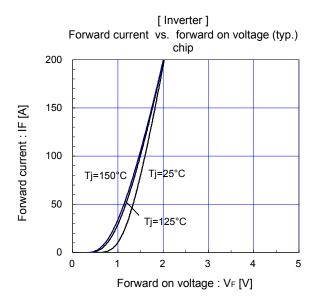
[ Inverter ]

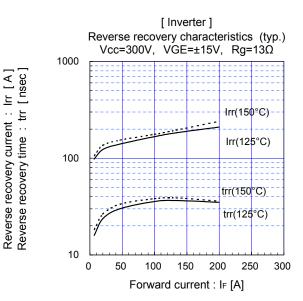
Reverse bias safe operating area (max.)

+VGE=15V,-VGE <= 15V, RG >=  $13\Omega$ , Tj =  $150^{\circ}$ C



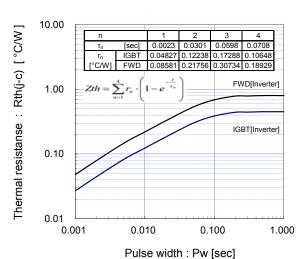
Collector-Emitter voltage : VcE [V] (Main terminals)

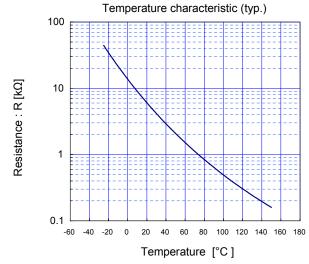




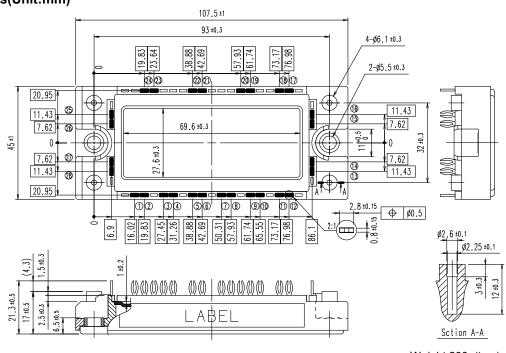
[Thermistor]

Transient thermal resistance (max.)



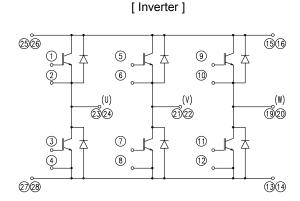


■ Outline Drawings(Unit:mm)



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# **■** Equivalent Circuit



[Thermistor]



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- Measurement equipment

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